Electronics Engg.

ENGINEERS ACADEMY ESE-2018 Mock Test Paper



- **1.** In a sky wave with a frequency of 50 MHz is incident on the D-region at an angle of 30° then the angle of refraction is
 - (a) 15° (b) 60°
 - (c) 30° (d) 5.5°
- 2. Tropospheric scatter communication is used for which frequency band ?
 - (a) HF (b) LF
 - (c) UHF (d) VLF
- **3.** Which one of the following technique is not suitable for automatic satellite tracking ?
 - (a) monopulse (b) step tracking
 - (c) conical scanning (d) lobe switching
- **4.** Communication satellite are allotted a bandwidth of 500 MHz. This can be increased by using
 - (a) frequency and polarisation reuse.
 - (b) time division multiplexing
 - (c) frequency division multiplexing
 - (d) triple modulator redundancy
- 5. If n_1 and n_2 are refractive indices of the core and cladding respectively, the maximum acceptance angle at air-core interface should be.
 - (a) $\tan^{-1} \frac{n_2}{n_1}$ (b) $\sin^{-1} \sqrt{n_2^2 n_1^2}$ (c) $\sin^{-1} \sqrt{n_1^2 - n_2^2}$ (d) $\tan^{-1} \frac{n_1}{n_2}$
- 6. A certain fibre has refractive index of core $n_1 = 1.40$ and that of cladding $n_2 = 1.05$. Its numerical aperture will be
 - (a) 0.8575 (b) 0.9260
 - (c) 0.3500 (d) 0.1585
- 7. The topology with highest reliability is
 - (a) BUS (b) STAR
 - (c) RING (d) MESH
- **8.** The file transfer protocol FTP requires a reliable transport service. Which protocol of the TCP/IP suite does it use ?
 - (a) TCP (b) UDP
 - (c) Telnet (d) None of these

- **9.** Two microwave signal traveling in the free space have a path length difference of 3 cm when operating at 10 GHz. What is relative phase difference of the signals?
 - (a) 2π (b) π
 - (c) 3π (d) 4π
- 10. Suppose that everyone in a group of N people wants to communicate secretly with the N-1 others using symmetric key cryptographic system. The communication between any two persons should not be decodable by the others in the group. The number of keys required in the system as a whole to satisfy the confidentiality requirement is
 - (a) 2 N (b) N(N-1)
 - (c) N(N-1)/2 (d) $(N-1)^2$
- 11. The Esland B formula can be used to calculate
 - (a) Total traffic (b) blocking
 - (c) lines (d) All of the above
- **12.** Which of the following is an analog cellular phone system using FDMA?
 - (a) AMPS (b) CDMA
 - (c) NAMPS (d) both (a) and (c)
- **13.** The skip distance is
 - (a) same for each layer
 - (b) independent of frequency
 - (c) independent of state of ionization
 - (d) independent of transmitted power
- 14. In an LOS communication system, the ground below the direct path is the first Fresnel zone and is smooth reflecting. The phase difference between direct and reflected waves at the receiving antenna will be
 - (a) 180° (b) 360°
 - (c) 270° (d) 450°
- **15.** What is the goal of CTS.
 - (a) Maximum IR (b) Minimum EM
 - (c) Mini Skew (d) Mini Slack
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- 16. Usually hold is fixed.
 - (a) Before placement (b) After placement
 - (c) Before CTS (d) After CTS
- 17. Filler cells are added _____
 - (a) Before placement of standard cells
 - (b) After placement of standard cells
 - (c) Before floor planning
 - (d) Before digital routing
- 18. Search and repair is used for
 - (a) Reducing IR drop (b) Reducing DRC
 - (c) Reducing EM (d) None
- **19.** With the use of following device (s) and cables can a LAN based on star topology be setup
 - (a) router (b) bridge
 - (c) switch (d) repeater
- **20.** More IR drop is due to
 - (a) Increase in metal width
 - (b) Increase in metal length
 - (c) Dicrease the metal length
 - (d) Let of metal layers
- **21.** The minimum height and width of a cell can occupy in the design is called as
 - (a) Unit tile cell (b) Multi heighten cell
 - (c) LVT cell (d) HVT cell
- 22. CRPR stands for
 - (a) Cell convergence pessimism removal
 - (b) Cell convergence preset removal
 - (c) Clock convergence pessimism removal
 - (d) Clock convergence preset removal
- **23.** Delay between shortest path and longest path in clock is called
 - (a) Useful skew (b) Local skew
 - (c) Global skew (d) Slack
- 24. Three primary physical character of digital design are
 - (a) Speed (b) Area
 - (c) Power (d) All of above

- 25. In OCV timing check, for setup time
 - (a) Maximum delay used for launch path and minimum delay for capture path
 - (b) Minimum delay for launch path and maximum delay for capture path
 - (c) Both maximum delay is used for launch path and capture
 - (d) Both minimum delay is used for launch and capture paths

List-II

- 26. Match the following List-I
 - A. n-channel JFET
 - B. Depletion MOSFET
 - C. p-channel JFET
 - **D.** Enhancement MOSFET 4. G ↔

Codes :	Α	В	С	D
(a)	3	4	2	1
(b)	3	2	4	1
(c)	2	4	1	3
(d)	3	4	1	2

27. In figure $V_{BE} = 0.6V$, $\beta = 99$. Then V_C and I_C are



- (a) 4.6 V and 0.02 mA respectively
- (b) 4.6 V and 1.98 mA respectively
- (c) 9.3 V and 1.98 mA respectively
- (d) 9.3 V and 0.02 mA respectively

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28. *Assertion* (*A*) : CE amplifier is the most widely used BJT amplifier

Reason (R): CE amplifier has zero phase difference between input and output

- (a) Both A and R are correct and R is correct explanation of A
- (b) Both A and R are correct and R is not correct explanation of A
- (c) A is correct R is wrong
- (d) A is wrong R is correct
- **29.** *Assertion* (*A*) : A push-pull amplifier gives more output per active device for a given amount distortion.

Reason (R): Even harmonics are absent in the output of push-pull amplifier.

- (a) Both A and R are correct and R is correct explanation of A
- (b) Both A and R are correct and R is not correct explanation of A
- (c) A is correct R is wrong
- (d) A is wrong R is correct
- **30.** Consider the following statements.

Timer 555 can be used as

- 1. monostable multivibrator
- 2. bistable multivibrator
- 3. astable multivibrator

Which of the above statements are correct?

- (a) 1 & 2 (b) 1 & 3
- (c) 2 & 3 (d) 1, 2 & 3
- **31.** Consider the following statements.
 - 1. ECL has least propagation delay
 - 2. TTL has largest fan out
 - 3. CMOS has highest noise margin
 - 4. TTL has lowest power dissipation
 - Which of these are correct?
 - (a) 1 & 3 (b) 2 & 4
 - (c) 3 & 4 (d) 1 & 2

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32. A DRAM cell which holds 5V has to be refreshed every 20 ms so that the stored voltage does not fall by more than 0.5V. If the cell has a constant discharge current of 0.1 pA, the storage capacitance of cell is

(a) 4×10^{-6} F (b) 4×10^{-9} F

(c) 4×10^{-12} F (d) 4×10^{-15} F

- **33.** For a junction FET in the cut off region, as the drain voltage is increased, the drain current
 - (a) becomes zero
 - (b) remains constant
 - (c) abruptly decreases
 - (d) abruptly increases
- **34.** The maximum theoretical efficiency of a class B push-pull transistor amplifier as approximately.
 - (a) 78.6 % (b) 50 %
 - (c) 25% (d) 70.7 %
- 35. The coupling capacitor in amplifier circuits
 - (a) does not affect DC biasing
 - (b) affects DC biasing to some extent
 - (c) affects DC biasing
 - (d) both (b) and (c)
- **36.** The bandwidth of an n-stage tuned amplifier, with each stage having a bandwidth of B is given by

(a)
$$\frac{B}{\sqrt{n}}$$
 (b) $\frac{B}{n}$
(c) $\frac{B}{\sqrt{2^{1/n}-1}}$ (d) $B\sqrt{2^{1/n}-1}$

37. Find V_0 and I_1 in the given circuit



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	 (a) 9.7 V, 0.1667 mA (b) 9.3 V, 1.667 mA (c) 9.3 V, 0.1667 mA (d) 9.7 V, 9.5 mA 	42.	To avoid ther analog circuit, be such that, (a) $V_{CE} = \frac{1}{2}$
38.	 Which of the following pairs of semiconductors and current carriers is correctly matched ? (a) Intrinsic → No. of electrons = No. of holes. (b) n-type → No. of electrons < No. of holes. 	43.	(c) $V_{CE} \ge \frac{1}{2}$ The probabil occupies the (>0°k)
39.	 (c) p-type → No. of electrons > No. of holes. (d) Bulk → No. of electrons < No. of holes. An LED mode using GaAs emits radiation in (a) visible region 	44.	(a) 0 (c) 0.5 The voltage approximately (a) $(g_m r_o)/2$

- (b) Infrared region
- (c) microwave frequency region
- (d) ultraviolet region
- 40. Which of the following is not a linear IC?
 - (a) Comparator
 - (b) Passive filter
 - (c) Voltage controlled oscillator
 - (d) Phase locked loop
- **41.** Find the correct match between Group-I and Group-II

	Grou	ıp-I		Gro	up-II	
А.	Varac	tor di	iode	1.	Voltage	reference
В.	PIN	diode		2.	High switch	frequency
C.	Zener	diod	e	3.	Tuned	circuit
D.	Schot	tky d	iode	4.	Curren	t controlled
					attenua	tor
Codes :	Α	В	С	D		
(a)	4	2	1	3		
(b)	2	4	1	3		
(c)	3	4	1	2		
(d)	1	3	2	4		

-		_
To avoid thermal runaw	ay in the design of	an
analog circuit, the operation	ing point of BJT show	uld
be such that, It satisfied	l the condition	
1	1	

(a)
$$V_{CE} = \frac{1}{2} V_{CC}$$
 (b) $V_{CE} < \frac{1}{2} V_{CC}$
(c) $V_{CE} \ge \frac{1}{2} V_{CC}$ (d) $V_{CE} \le 0.78 V_{CC}$

43. The probability that an electron in a metal occupies the fermi level at any temperature $(>0^{\circ}k)$

(a)	0	(b)	0.1
(c)	0.5	(d)	1

44. The voltage gain of basic CMOS is approximately

(a)
$$(g_m r_o)/2$$
 (b) $2g_m r_o$
(c) $\frac{1}{2g_m r_o}$ (d) $2g_m/r_o$

45. Assertion (A) :When diode used as rectifier the reverse breakdown voltage should not be exceeded.

Reason (R) : A high reverse voltage can destroy a p-n junction.

- (a) Both A and R are true and R is correct explanation of A.
- (b) Both A and R are true and R is not correct explanation of A.
- (c) A is true but R is wrong
- (d) A is false but R is true.
- 46. Assertion (A) : A JFET behaves as a resistor when $V_{GS}\,<\,V_{p}$

Reason (R) : When $V_{GS} < V_p$ the drain current in a JFET is almost constant.

- (a) Both A and R are true and R is correct explanation of A.
- (b) Both A and R are true and R is not correct explanation of A.
- (c) A is true but R is wrong
- (d) A is false but R is true.



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47. In given figure a silicon diode is carrying a constant current of 1mA. When the temperature of the diode is 20° C, V_{D} is found to be 700 mV. If the temperature rises to 40° C. V_{D} becomes approximately equal to



- **48.** Consider the following statements : The function of oxide layer in an IC device is to
 - 1. Mask against diffusion or non implant
 - 2. Insulate the surface electrically
 - 3. Increase the melting point of silicon.
 - 4. Produce a chemically stable point.

Correct statement is

- (a) 1, 3 & 4 (b) 2, 3 & 4
- (c) 1, 2 & 4 (d) 1, 2 & 3
- **49.** *Assertion* (*A*) : The image charge must be located in the conducting region.

Reason (R): Due to image charge in conducting region, it satisfy the laplace equation.

- (a) Both A and R are true & R is the correct explanation of A
- (b) Both A and R are true & R is not the correct explanation of A
- (c) A is true but R is false
- (d) A is false but R is true
- 50. Consider the following statement
 - (i) Electric field intensity depends on medium.
 - (ii) Electric flux density depends on medium.

Which is the correct statement among above

- (a) only (i) (b) only (ii)
- (c) both (i) and (ii) (d) None

51. Uniform plane wave is given by

$$\vec{E} = 8\cos(\omega t - 4x - 3z)\hat{a}_y \frac{V}{m}$$

is incident on the dielectric slab (Z = const.) with $\mu_r = 1$, $\epsilon_r = 2.5$, $\sigma = 0$. Wave is

- (a) Horizontally polarized
- (b) Vertically polarized
- (c) Elliptically polarized
- (d) Circularly polarized
- **52.** Two identical co-axial circular coil carry the same current but in opposite direction. The magnitude of the magnetic field B at a point on the axis midway between the coil is
 - (a) Zero
 - (b) Same as that produced by one coil
 - (c) Twice that produced by one coil
 - (d) Half that produced by one coil.
- 53. An air filled waveguide having cross-section 5 $\text{cm} \times 2$ cm is operated at 15 GHz. The component of electric field in the waveguide is given as

 $E_z = 20 \sin 40\pi x \sin 50 \pi y e^{-j\beta z} V/m$

The mode which being propagated is

- (a) TE_{21} (b) TM_{21}
- (c) TE_{12} (d) TM_{12}
- 54. Input impedance of short circuited lossless line
 - of length l where $\frac{\lambda}{4} < l < \frac{\lambda}{2}$ will be.
 - (a) Resistive (b) Inductive
 - (c) Capacitive (d) None

55. Charge needed within unit sphere centred at origin

for producing a potential field $V = -\frac{6r^5}{\epsilon_0}$ for $r \le 1$ is

- (a) $30 \ \pi C$ (b) $120 \ \pi C$
- (c) $60 \ \pi C$ (d) $180 \ \pi C$





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- 56. Radiation intensity of dipole at frequency f is I. Radiation intensity of dipole at frequency $\frac{f}{4}$ will be
 - (a) $\frac{I}{4}$ (b) 4I
 - (c) 16I (d) $\frac{I}{2}$
- **57.** An Antenna consisting of 50 m long vertical conductor operates over a perfectly conducting ground plane. It is base fed at a frequency of 600 KHz. The radiation resistance of antenna in ohms is

(a)
$$\frac{2\pi^2}{5}$$
 (b) $\frac{\pi^2}{5}$
(c) $\frac{4\pi^2}{5}$ (d) $20\pi^2$

- **58.** A (75 j40) load is connected to the co-axial line of $Z_0 = 75 \Omega$ at 6 MHz. The load matching on the line can be accomplished by connecting
 - (a) A short circuit stub at the load
 - (b) An inductance at the load
 - (c) A short circuit stub at a specific distance from the load
 - (d) A capacitance at a specific distance from the load
- 59. A plane wave is characterized by

 $\vec{E} = (0.5\hat{a}_x + e^{j\pi/2}\hat{a}_y)e^{j\omega t}e^{-j\beta z}$

The wave is

- (a) linear polarized
- (b) circularly polarized
- (c) elliptically polarized
- (d) unpolarized
- 60. The depth of penetration of EM wave in a medium having conductivity $\sigma \gg \omega \in$ at a frequency of 1 MHz is 25 cm. The depth of penetration at a frequency of 4 MHz will be

(c) 50 cm (d) 100 cm

- **61.** In a 100 turn coil, if flux through each turn is $(t^3 2t)$ mWb. The magnitude of induced emf in the coil at time t = 4 sec. is
 - (a) 46 mV (b) 56 mV (c) 4.6 V (d) 5.6 V
- 62. A plane intersects the coordinate axis at x = 2/3, y = 1/3, z = 1/2. What is the miller index of this plane?
 - (a) (932) (b) (432)
 - (c) (423) (d) (364)
- **63.** Find the correct relation?

(a)
$$\overline{P} = \varepsilon_0(\varepsilon_r - 1)\overline{E}$$
 (b) $\overline{P} = \left(\frac{\varepsilon_0}{\varepsilon_r - 1}\right)\overline{E}$
(c) $\overline{P} = \left(\frac{\varepsilon_0}{\varepsilon_r + 1}\right)\overline{E}$ (d) $\overline{P} = \varepsilon_0(\varepsilon_r + 1)\overline{E}$

64. There are 10^{27} HCL molecules per cubic meter in a vapour. Determine the orientational polarization at room temperature if the vapour is subjected to an electrical field of 10^6 V/m. The permanent dipole moment of HCL molecule being 1.04 debye unit.

1 debye unit = 3.33×10^{-30} coulomb - meter

- (a) 0.875 \times 10⁻³⁸ Farad meter²
- (b) 0.875×10^{-39} Farad meter²
- (c) 0.966×10^{-39} Farad meter²
- (d) 0.966 \times 10⁻⁶ Coulomb / meter²
- **65.** The magnetization M of a super conductor in a field of H is.
 - (a) Extremely small (b) -H
 - (c) -1 (d) Zero
- **66.** Which law is synonymous to the occurrence of diamagnetism?
 - (a) Ampere's law (b) Maxwell's law
 - (c) Coulomb's law (d) Lenz's law
- **67.** As per curie-weiss law, the magnetic susceptibility of a material varies as
 - (a) T^{-2} (b) 1/T
 - (c) T (d) T^2

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- 68. German silver contains.
 - (a) 12.5% Silver (b) 5% Silver
 - (c) 1% Silver (d) No Silver
- **69.** In HRC confridge fuse we use.
 - (a) Gold (b) Silver
 - (c) Copper (d) Aluminium
- **70.** If the frequency of light falling on a metal plate is doubled, the kinetic energy of emitted electrons will be:
 - (a) Exactly double
 - (b) Slightly more than double
 - (c) Slightly less than double
 - (d) Four times
- 71. Consider the following steps.
 - 1. Etching
 - 2. Exposure to UV radiation
 - 3. Stripping
 - 4. Developing

After a wafer has been coated with photoresist the correct sequence of these steps in photolithography is.

- (a) 2, 4, 3, 1 (b) 2, 4, 1, 3
- (c) 4, 2, 1, 3 (d) 4, 2, 3, 1
- **72.** An advantage of semiconductor strain gauge as compared to conventional strain gauge is
 - (a) Excellent (b) High fatigue life
 - (c) Smaller size (d) All of these
- **73.** Creation of temperature difference by applying a voltage between two electrrode connect to a sample of semiconductor material.
 - (a) Pelteir effect
 - (b) Seeback effect
 - (c) Thomson effect
 - (d) Half effect

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74.	In a two - wattmeter method of measuring power
	in a balanced 3-phase circuit, the ratio of the
	two wattmeter reading is 2 : 1. The circuit power
	factor is

- (a) 0.707 (b) 0.5
- (c) 0.866 (d) 1
- **75.** What is meant by a single chip data acquisition system
 - (a) A single integrated circuit containing A DAC and a demultiplexer
 - (b) A single integrated circuit containing on ADC and a multiplexer
 - (c) A single IC containing all the element of DAS
 - (d) A single IC Containing an ADC and A DAC
- **76.** A signal contains components with frequencies up to 10 KHz, although no useful information is contained at frequencies 6 KHz. What is the minimum frequency at which the signal should be sampled?

(a) 6 kHz	(b) 12 kHz

- (c) 14.4 kHz (d) 20 kHz
- **77.** Match List-I (instrument type) with List-II (used for) the following

List-I List-II

A.	PMMC	1. DC only
B.	Moving Iron	2. AC only
	conected with CT	

- C. Reactifier
- **D.** Electrodynamometer

Codes :	Α	В	С	D
(a)	1	2	1	3
(b)	1	3	1	2
(c)	1	2	3	3
(d)	3	1	2	2

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3. AC and DC

suring of 3-j eter method, 7. The power (t (c ammeter has extending its ant required (c tage limiting reading of 8 iaving a guar reading is % (c (A):The scree thor on the i	phase bi the read factgor b) 0.602 d) 0.902 an inter s range of resist b) 22.22 d) 50.0 g error, if 8.3V wi ranteed b) 0.181 d) 18.10 een of a	alanced load b ding are 100 V of the load is nal resistance of to measure 50 cance Ω Ω n the case of a th a 0 to 150 accuracy of 19	y Cod 7 5 83.	les : (a) (b) (c) (d) A 12 MH2 reso (a) 2 (c) 4 In ca meth indu	A 1 3 1 2 bit of z clock lution 2.44 n 0.02 V ase of p nod in	B 2 2 1 4 counter t c. If the s output is nV	C 3 1 4 3 cype AD full scal s (b) 2 (d) 0 easurem ced 3-\$	D 4 4 2 2 OC counter u e output is 4 2.4 mV 0.02 mV ent by two w system with	ıses a ⊦10V, i
eter method, /. The power (t (c ammeter has extending it: int required (t extending it: int required (c tage limiting reading of 8 iaving a guar reading is % (c (A):The scree- hor on the i	the read the read factgor (b) 0.602 (d) 0.902 (an inter (s) range (of resist (c) 22.22 (d) 50.0 (c) error, if (8.3V with ranteed (c) 0.181 (d) 18.10 (c) (c) (c) (c) (c) (c) (c) (c) (c) (c)	ding are 100 V of the load is nal resistance of to measure 50 cance Ω Ω n the case of a th a 0 to 150 accuracy of 19 %	f 5 83. 7 84.	 (a) (b) (c) (d) A 12 MH2 reso (a) 2 (c) 4 In ca meth indu 	1 3 1 2 bit of z clock lution 2.44 n 0.02 V ase of p nod in	2 2 1 4 counter t c. If the t output is nV	3 1 4 3 cype AD full scal s (b) 2 (d) 0 easurem ced 3-\$	4 4 2 2 DC counter u e output is + 2.4 mV 0.02 mV ent by two w system with	ıses a ⊦10V, i ′attmete
7. The power (t) (c) ammeter has extending it: ant required (c) tage limiting reading of 8 having a guar reading is % (c) (A):The scree hor on the i	 factgor o) 0.602 an inter s range of resist o) 22.22 d) 50.0 g error, in 8.3V with ranteed o) 0.181 d) 18.10 een of a 	of the load is nal resistance of to measure 50 cance Ω Ω n the case of a th a 0 to 150 accuracy of 19 %	f 83.	(b) (c) (d) A 12 reso (a) (c) In ca meth indu	3 3 1 2 bit of z clock lution 2.44 n 0.02 V ase of p nod in	2 1 4 counter t t. If the f output is nV y power me a balance	1 4 3 cype AD full scal s (b) 2 (d) (easurem ced 3-\$	4 2 2 0C counter u e output is 4 2.4 mV 0.02 mV ent by two w system with	ıses a ⊦10V, i
(t (c ammeter has extending it: ant required (t extage limiting reading of & aving a guar reading is % (t % (c (A):The scree hor on the i	 b) 0.602 c) 0.602 an inter an inter s range of resist c) 22.22 <lic) 24.22<="" li=""> c) 22.22 <lic) 24.22<="" li=""> <lic) 24.22<="" <="" td=""><td>nal resistance of to measure 50 cance Ω Ω n the case of a th a 0 to 150 accuracy of 19 %</td><td>f 83. 84.</td><td> (c) (d) A 12 MH2 reso (a) 2 (c) 0 In ca meth indu </td><td>3 1 2 bit of z clock lution 2.44 n 0.02 V asse of p nod in</td><td>1 4 counter t c. If the f output is nV power ma a baland</td><td>4 3 full scal s (b) 2 (d) 0 easurem ced 3-ϕ</td><td>2 2 DC counter u e output is + 2.4 mV 0.02 mV ent by two w system with</td><td>uses a ⊦10V, i rattmet</td></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)></lic)>	nal resistance of to measure 50 cance Ω Ω n the case of a th a 0 to 150 accuracy of 19 %	f 83. 84.	 (c) (d) A 12 MH2 reso (a) 2 (c) 0 In ca meth indu 	3 1 2 bit of z clock lution 2.44 n 0.02 V asse of p nod in	1 4 counter t c. If the f output is nV power ma a baland	4 3 full scal s (b) 2 (d) 0 easurem ced 3- ϕ	2 2 DC counter u e output is + 2.4 mV 0.02 mV ent by two w system with	uses a ⊦10V, i rattmet
(c ammeter has extending its ant required ? (c ? (c tage limiting reading of 8 aving a guar reading is % (c (A):The scree hor on the i	 d) 0.902 an inter s range of resist o) 22.22 d) 50.0 g error, if 8.3V with ranteed b) 0.181 d) 18.10 een of a 	nal resistance of to measure 50 cance Ω Ω n the case of a th a 0 to 150 accuracy of 19 %	f 83. 1 7 84.	 (d) A 12 MH2 reso (a) 2 (c) 0 In ca meth indu 	1 2 bit of z clock lution 2.44 n 0.02 V ase of p nod in	4 counter t c. If the f output is nV power ma a baland	3 sype AD full scal s (b) 2 (d) (easurem ced 3- ϕ	2 2 DC counter u e output is + 2.4 mV 0.02 mV ent by two w system with	uses a ⊦10V, i ′attmet
ammeter has extending it int required ? (b ? (c itage limiting reading of 8 naving a guar reading is % (b % (c (A):The scree hor on the i	an inter s range of resist o) 22.22 d) 50.0 g error, in 8.3V wir ranteed b) 0.181 d) 18.10 een of a	nal resistance of to measure 50 ance Ω Ω n the case of a th a 0 to 150 accuracy of 19 %	f 3 83. 7 84.	 (d) A 12 MH2 reso (a) 2 (c) 4 In ca meth indu 	2 bit of z clock lution 2.44 n 0.02 V ase of p nod in	4 counter t c. If the output is nV power ma a baland	5 Sype AD full scal s (b) 2 (d) (easurem ced 3- ϕ	2 DC counter u e output is 4 2.4 mV 0.02 mV ent by two w system with	ıses a ⊦10V, i ′attmet
extending it ant required (to the second sec	s range of resist (b) 22.22 (c) 22.2	to measure 50 cance Ω Ω n the case of a th a 0 to 150 accuracy of 19 %	n 84.	A 12 MH2 reso (a) 2 (c) 0 In ca meth indu	2 bit of z clock lution 2.44 n 0.02 V ase of j nod in	counter t a. If the soutput is nV power ma a baland	ype AD full scal s (b) 2 (d) 0 easurem ced 3- ϕ	C counter u e output is + 2.4 mV 0.02 mV ent by two w system with	ıses a ⊦10V, i
unt required 2 (t 2 (t 2 (c tage limiting reading of 8 naving a guan reading is % (c % (c (A):The scree hor on the i	of resist b) 22.22 d) 50.0 g error, if 8.3V wi ranteed b) 0.181 d) 18.10 een of a	cance Ω Ω n the case of a th a 0 to 150 ³ accuracy of 19 %	n 7 84.	(a) (c) (In ca meth indu	2 clock lution 2.44 n 0.02 V ase of j nod in	output is nV power ma a baland	(b) 2 (d) (ceasurem ced 3- ϕ	2.4 mV 0.02 mV ent by two w	rattmet
2 (t 1 (c 1	 b) 22.22 c) 50.0 f c) error, if error, if er	Ω Ω n the case of a th a 0 to 150 ^v accuracy of 19 %	n 7 84.	(a) (c) (In ca meth indu	2.44 n 0.02 V ase of j nod in	nV power ma a balana	(b) 2 (d) (easurem ced 3-\$	2.4 mV 0.02 mV ent by two w system with	'attmet
2 (c atage limiting reading of 8 reading a guar reading is % (c % (c (A): The scree hor on the i	 d) 50.0 error, if 8.3V with ranteed b) 0.181 d) 18.10 een of a 	Ω n the case of a th a 0 to 150 accuracy of 19 %	n 7 84.	(a) (c) In ca meth indu	0.02 V ase of j nod in	power me a balane	(d) (easurem ced 3-\$	0.02 mV ent by two w system with	'attmet
tage limiting reading of { naving a guan reading is % (b % (c (A):The scree thor on the i	(error, it 8.3V wi ranteed (b) 0.181 (d) 18.10 (cen of a	n the case of a th a 0 to 150 ^v accuracy of 19 %	n 7 84.	(c) In ca meth indu	0.02 v ase of j nod in	power me a balane	(d) (easurem ced 3-¢	0.02 mV ent by two w system with	vattmet
reading of 8 naving a guar reading is % (b % (c (A):The scree thor on the i	8.3V wi ranteed b) 0.181 d) 18.10 cen of a	th a 0 to 150 ^v accuracy of 19 %	7 84.	In ca meth indu	ase of j nod in	oower me a balane	easurem ced 3-φ	ent by two w system with	vattmet
reading is % (t % (c (A):The scre hor on the i	o) 0.181 d) 18.10 een of a	%		muu	CITIVA	heo		<i>sjsvuu</i>	ı a pu
% (t % (c (<i>A</i>):The scre hor on the i	d) 0.181 d) 18.10 een of a	%		(a)	Both t	he wattr	neter wi	ill indicate t	he san
% (((A):The scre (hor on the i	d) 18.10 en of a			(a) Both the wattineter will indicate the but of opposite sign(b) Both the wattineters will indicate ze					
(A):The scre hor on the i	en of a	%							zero
Assertion (A): The screen of a CRT is coated with phosphor on the inside				(c) Both the wattmeter will indicate same vlaue and of the same sign					
Reason (\mathbf{R}): Phosphor absorbs the KE of the bombarding electrons and reemits energy at a frequency in the visible region.				(d)	One work	vattmeter non-zero	will in value	ndicate zero	and th
A and R are ation of A.	e true ai	nd R is correc	85. t	Whi trans	sducer.	the fo	ollowin	ig is not j	primai
and R are t	rue and	R is not correct	t	(a)	Bourd Bollou	on tubes			
ation of A.	inc and	K is not correct	ι	(b) Bellows (c) LVDT (for displacement measurement)					
ue but P is	falsa			(d) LVDT (for pressure measurement)					
	Taise.		86.	Mecl	hanical	impeda	nce is f	he ratio of	
alse but R is	true.			(a) 1	ms fo	rce to rn	ns veloc	zitv	
-I with List-	·II			(b) 1	ms fo	rce to rn	ns displa	acement	
	List-	Ι		(c) 1	ms ve	locity to	rms di	splacement	
r	1. Me	asurement o	f	(d) 1	None of	of the ab	ove	~ F	
	los	s angle in	a 87.	Find	the ir	verse la	place tra	ansform of	
	diel	ectric					2s +	12	
ım analyzer	2. Me	asurement o	f			f(s) =	$=\frac{1}{s^2+2s}$	$\overline{s+5}$	
	free	luency		(a) 2	2 e ^{-t} si	n 2t + 5	e ^{-t} cos	2t	
ng bridge	3. Me	asurement of		(b) 2	2 e ^{-t} si	n 2t – 5	e ^{-t} cos	2t	
	insu	ilation resistance	e	(c) 5	5 e ^{-t} si	n 2t + 2	e ^{-t} cos	2t	
	4. Me	asurement o momics	f	(d) 5	5 e ^{-t} si	n 2t – 2	e ^{-t} cos	2t	
ו ג	im analyzer ig bridge counter	List-J 1. Me los diel um analyzer 2. Me frec g bridge 3. Me insu counter 4. Me har	List-II 1. Measurement o loss angle in a dielectric am analyzer 2. Measurement o frequency ag bridge 3. Measurement of insulation resistance counter 4. Measurement o harmomics ear Khandaka Hospital	List-II 1. Measurement of loss angle in a dielectric 1. Measurement of frequency 1. Measurement of frequency 1. Measurement of insulation resistance 2. Measurement of insulation resistance 2. Measurement of harmomics	List-II (c) i (c) i (c) i (c) i (c) i (d) I loss angle in a dielectric (a) 2 (c) i (c) i (List-II (b) fins for (c) rms veresting to a dielectric fr 1. Measurement of loss angle in a dielectric (c) rms veresting to a dielectric fr analyzer 2. Measurement of frequency (a) 2 e ^{-t} si (b) 2 e ^{-t} si (c) 5 e ^{-t} si	List-II(b) This force to The (c) rms velocity to (d) None of the ab Find the inverse lap (d) None of the ab Find the inverse lap Find the inverse lap (d) None of the ab Find the inverse lap (a) $2 e^{-t} \sin 2t + 5$ (b) $2 e^{-t} \sin 2t + 5$ (c) $5 e^{-t} \sin 2t - 5$ (c) $5 e^{-t} \sin 2t - 2$ (d) $5 e^{-t} \sin 2t - 2$ ear Khandaka HospitalImage Second Se	List-II (b) This force to this disprive (c) rms velocity to rms di (c) rms velocity to rms di (d) None of the above Find the inverse laplace tra- (d) None of the above (e) None of the above (f) None of the above (f) None of the above (h) 2 e ^{-t} sin 2t + 5 e ^{-t} cos (h) 2 e ^{-t} sin 2t + 2 e ^{-t} cos (h) 5 e ^{-t} sin 2t + 2 e ^{-t} cos (h) 5 e ^{-t} sin 2t - 2 e ^{-t} cos (h) 5 e ^{-t} sin 2t - 2 e ^{-t} cos (h) 5 e ^{-t} sin 2t - 2 e ^{-t} cos (h) 5 e ^{-t} sin 2t - 2 e ^{-t} cos (h) 5 e ^{-t} sin 2t - 2 e ^{-t} cos (h) 5 e ^{-t} sin 2t - 2 e ^{-t} cos (h) 5 e ^{-t} sin 2t - 2 e ^{-t} cos (h) 5 e ^{-t} sin 2t - 2 e ^{-t} cos (h) 5 e ^{-t} sin 2t - 2 e ^{-t} cos (h) 5 e ^{-t} sin 2t - 2 e ^{-t} cos (h) 5 e ^{-t} sin 2t - 2 e ^{-t} cos (h) 5 e ^{-t} sin 2t - 2 e ^{-t} cos	List-II(b) This force to this displacement1. Measurement of loss angle in a dielectric(c) rms velocity to rms displacementam analyzer 2. Measurement of frequency87.ag bridge3. Measurement of insulation resistance87.counter4. Measurement of harmomics(b) 2 e ^{-t} sin 2t + 5 e ^{-t} cos 2t (c) 5 e ^{-t} sin 2t + 2 e ^{-t} cos 2t (d) 5 e ^{-t} sin 2t - 2 e ^{-t} cos 2tcear Khandaka HospitalALA CHARING CONCLUSE CONCLUSE

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- (a) PID controllers
- (b) Lag-lead compensators
- (c) Lead or lag compensators
- (d) None of above

89. Obtain the transfer function $\frac{E_0(s)}{E_i(s)}$ of the bridge



(a)
$$\frac{\text{RC}_{1}\text{RC}_{2}\text{s}^{2} + 2\text{RC}_{2}\text{s} + 1}{\text{RC}_{1}\text{RC}_{2}\text{s}^{2} + (2\text{RC}_{2} + \text{RC}_{1})\text{s} + 1}$$

(b)
$$\frac{\text{RC}_{1}\text{RC}_{2}\text{s}^{2} + (2\text{RC}_{1} + \text{RC}_{1})\text{s} + 1}{\text{RC}_{1}\text{RC}_{2}\text{s}^{2} + 2\text{RC}_{2}\text{s} + 1}$$
$$\text{RC}_{2}\text{C}_{2}\text{s}^{2} + 2\text{RC}_{2}\text{s} + 1$$

(c)
$$\frac{RC_1C_2s^2 + 2RC_2s + 1}{RC_1C_2s^2 + (2RC_2 + RC_1)s + 1}$$

(d) None of above

90. *Assertion* (*A*) : The steady state response, of a stable, linear, time invariant system, to sinusoidal

input depends on initial conditions.

Reason (**R**): Frequency response, in steady state, is obtained by replacing s in the transfer function by $j\omega$.

- (a) Both A and R are correct and R is correct explanation of A
- (b) Both A and R are correct but R is not correct explanation of A
- (c) A is correct but R is wrong
- (d) R is correct but A is wrong
- **91.** Assertion (A): An LTI discrete system represented by the difference equation

y(n+2) - 5y(n+1) + 6y(n) = x(n) is unstable.

Reason (R): A system is unstable if the roots of the characteristic equation lie outside the unit circle.

- (a) Both A and R are correct and R is correct explanation of A
- (b) Both A and R are correct but R is not correct explanation of A
- (c) A is correct but R is wrong
- (d) R is correct but A is wrong
- 92. A lag, lead compensator is essentially a
 - (a) low pass filter, High pass filter
 - (b) low pass filter, low pass filter
 - (c) High pass filter, Band pass filter
 - (d) High pass filter, low pass filter
- 93. In bode diagram (log magnitude plot) the factor $\frac{1}{i\omega}$ in the transfer function having slope
 - (a) -20 dB/octave (b) -2 dB/octave
 - (c) 10 dB/octave (d) 6 dB/octave
- **94.** A control system shown in figure what is the sensitivity of the system transfer function T with respect to k and H respectively. [where k = 10V/

rad, H = 10 V/rad and G(s) =
$$\frac{100}{s(s+1)}$$

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(a)
$$1, \frac{s(s+1)}{s^2 + s + 1000}$$

(b) $\frac{1000}{s^2 + s + 1000}$, 1

(c)
$$1, -\frac{1000}{s^2 + s + 1000}$$

(d)
$$\frac{1000}{s^2 + s + 1000}, -\frac{1000}{s^2 + s + 1000}$$

95. Match list-I (compensation) with list-II (characteristic) and select the correct answer using the code given below the lists.

	List-I			Lis	t-II	
A.	lead		1.	Att	enuation	
B.	Rate		2.	Increase bandwidth		width
C.	Lag		3.	Inc	rease damp	oing factor
D.	Lag-lead		4.	Sec	ond order	
Codes :	Α	B		С	D	
(a)	1	3		4	2	
(b)	2	3		1	4	
(c)	2	4		1	3	
(d)	1	3		2	4	

96. Consider the feedback system shown in figure



For this system root locus is

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97. Assertion (A) : If the venin's equivalent of a circuit is known, its norton equivalent is also known.

Reason(R): Norton's equivalent is reciprocal of thevenin's equivalent.

- (a) Both A and R are true and R is the correct explanation of A
- (b) Both A and R are true, but R is not the correct explanation of A
- (c) A is true, but R is false
- (d) R is true, but A is false
- **98.** Five cells, each with an emf of 2V and internal resistance of 0.5Ω are connected in series. The resulting battery will have
 - (a) An e.m.f. of 2V and an internal resistance of 0.5 Ω
 - (b) An e.m.f. of 10V and an internal resistance of 2.5 Ω



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- (c) An e.m.f. of 2V and an internal resistance of 0.1 Ω
- (d) An e.m.f. of 10V and an internal resistance of 0.15 Ω
- 99. Which of the following statement is false?
 - (a) A leclancha cell is suitable for use in torches
 - (b) A nickel-cadmium cell is an example of primary cell
 - (c) A secondary cell may be recharged after used
 - (d) when a cell is being charged its terminal potential difference exceeds the cell emf
- **100.** Consider the following statement regarding the batteries.
 - 1. A zinc carbon battery is rechargeable and is not classified as hazardous
 - 2. A nickel cadmium battery is not rechargeable and is classified as hazardous
 - 3. A lithium battery is used in watches and is not rechargeable
 - 4. The negative pole of a dry cell is made of zinc.

Which of the statements is true?

- (a) 1, 2, and 3 (b) 1, and 4
- (c) 3 and 4 (d) 1 and 3
- 101. Consider the following statement regarding KCL & KVL
 - 1. KCL is used for DC and AC analysis.
 - 2. KCL states that algebraic sum of all current entering and leaving at node is zero
 - 3. KVL is given idea about conservation of energy while KCL for conservation of charge
 - 4. KVL is give idea about conservation of charge while KCL for conservation of energy which Of the following statement is WRONG ?
 - (a) 1, 2, and 3 (b) 1 and 2
 - (c) 4 Only (d) 1 Only

- **102.** Faraday's law of induction is the fundamental operating principle of
 - (a) Generator
 - (b) Transformers
 - (c) Inductors
 - (d) All of these
- **103.** In dc motor, which can provide zero speed regulation of full load without any controller
 - (a) series
 - (b) shunt
 - (c) cumulative compound
 - (d) differential compound
- **104.** Match list-I (Performance variable) with List-II (Proportional to) and select the correct answer using the codes given below

List-I List-II

- A. Armature emf(E) 1. Flux (ϕ), Speed(ω)
 - Armature current (I_a)
- B. Developed torque(T) 2. ϕ and ω only
- C. Developed power(P) 3. ϕ and I_a only
 - 4. I_a and ϕ only

Code:	Α	В	С
(a)	3	4	1
(b)	3	2	1
(c)	2	3	4
(d)	2	3	1

- **105.** In a transformer, zero voltage regulation at full load is
 - (a) not possible
 - (b) possible of unity power factor load
 - (c) possible at leading power factor load
 - (d) possible at lagging power factor load
- **106.** The following motor definitely has permanent magnet rotor
 - (a) DC cumulated motor
 - (b) Brushless dc motor
 - (c) Stepper motor
 - (d) reluctance motor



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107.	07. Out of the following plant categories						Which one of the following address technique			g address technique is
	1. Nuclear						not used on 8	3085 mici	ropro	ocessor?
	2. Kun of river						(a) Register		(b)	Immediate
	3. P	ump sto	rage				(c) Register	Indirect	(d)	Relative
	4. L	hese loa	d nower	nlan	te are	113.	Which logica	l operatio	on is	performed by ALU of
	(a) 1 and 2 (b) 2 and 3						8085 to comp	plement a	nun	nber?
	(a) 1 (c) 1	2 and 2	1	(d)	1 and 4		(a) AND		(b)	NOT
108	Cons	, 2 and ·	+ follow	(u) vina	conclusion regarding		(c) OR		(d)	EX-OR
100.	nucle	ar powe	r plant	mg	conclusion regarding	114.	The saving	in powe	er in	n a DSBSC system
	I	list-I			List-II		modulated at	80% is		
	A. C	Control R	lods	1.	Graphite		(a) Nil		(b)	80%
	B. C	Coolant		2.	Uranium		(c) 75.76%		(d)	50%
	C. F	uel		3.	Boron	115.	The diode loa	ad in the o	discr	iminator of direct FM
	D. N	Ioderato	r	4.	Water		modulator has			
Cod	e: A	B	С		D		(a) 10 ns			
	(a) 1	3	2		4		(d) small tim	ne constai	nt	
	(b) 3	2	1		4		(c) large tim	e constan	ıt	
	(c) 3	4	2		1		(d) negligible	e time co	nsta	nt
	(d) 4	1	3		2	116.	RMS quantiz	ation erro	or in	a 64 step binary PCM
109.	A sm	aller air	gap in a	poly	phase induction motor		system with a	a referenc	e sca	ale from 0 to 6.4 volts
	(a) R	educe th	ne chanc	e of	crawling		(a) 0.04 Volt	Ţ	(b)	0.001 Volt
	(b) I	ncrease t	he start	ing p	ower factor		(c) 0.03 Volt	-	(d)	0.02 Volt
	(c) R	leduce th	ne chanc	e of	cogging	117.	The amplitude specturm of a Gaussian pulse is			
	(d) R	Reduce th	ne magn	etizir	ng current		(a) Uniform		(b)	a sine function
110.	The 1	ankine c	ycle effic	ciency	y of stream power plant		(c) Gaussian	l	(d)	An impulse function
	is					118.	Spectral dens	sity of flic	cker	noise varies as
	(a) 6	0-80%		(b)	45-80%		(a) f		(h)	f^2
	(c) 3	0-35%		(d)	20-30%		1		(0)	1
111.	In c	ase of a s	signal ba	nd lir	nited to f_m is sampled at		(c) $\frac{1}{f}$		(d)	$\frac{1}{f^2}$
	a ra	te less th	an $2f_m$, t	the co	onstructed signal will be	119.	Frequency fr	ogging is	usec	l in carrier system to
	(a)	distorted	lless				(a) reduce cr	oss talk	(b)	conserve frequencies
	(b)	small in	amplitu	de			(c) reduce d	istortion	(d)	All of the above
	(c)	having h	nigher fr	eque	ncies suppressed	120.	Number of ou	tout pins i	n 80	85 microprocessor are?
	(d)	distored				1200	(a) 21	ip at philo i	(h)	27
							(c) 23		(d)	25
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Cont	Gopal act: 01	lpura, Ton 41-654091	k Road, J 0, +91-809	aipur 44417	-18 177 Your GATEway IES & GATE & I	to Profession PSUs + JT(al Excellence	Nagar, T ntact: 0141	onk I -6540	Road, Jaipur-33 911, +91-8094441999

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- 121. In a super heterodyne receiver, the IF is 455 kHz. It it is tuned to 1200 kHz the image frequency will be
 - (a) 910 kHz (b) 1655 kHz
 - (c) 2110 kHz (d) 745 kHz
- **122.** If status signal $S_1 = 1 \& S_0 = 0$, which operation is performed?
 - (a) Read (b) Write
 - (c) Opcode fetch (d) None
- **123.** Crystal frequency in 8085 microprocessor is

(a) 8 MHz	(b) 3 MHz
(c) 6 MHz	(d) 4 MHz

124. A certain Network N feeds a load resistance R as shown in figure-I. It consumes a power of 'P'Watt. If an identical network is added as shown in figure-II the power consumed by R will be







- (a) less than P (b) equal to P
- (c) between P and 4P (d) more than 4P.

125. In the circuit, the voltage across 3Ω resistance is



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126. The circ	cuit shown	in the	figure	is equivalent	to a
load of					



- (c) $(15/4)\Omega$ (d) 2 Ω
- 127. Consider the following statements regarding driving-point admittance function having two complex conjugate poles.
 - 1. Closer the poles to $j\omega$ -axis, Higher Q of the circuit.
 - 2. Value of Q varies inversely as the damping ratio
 - 3. A circuit with low R has low quality.
 - Of these statements
 - (a) 1 and 3 are correct
 - (b) 1 and 2 are correct
 - (c) 2 and 3 are correct
 - (d) 1, 2 and 3 are correct
- **128.** An RLC resonant circuit has resonance frequency of 1.5 MHz and a bandwidth of 10 kHz. If C = 150 pF, then the effective resistance of the circuit will be
 - (a) 9.4 Ω (b) 4.7Ω (c) 10.75 Ω (d) 29.5 Ω
- **129.** The y_{21} parameter of the network shown in the given figure will be



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130. Which one of the following is positive real function?

(a)
$$\frac{s^2 + 3s^2 + 2s + 1}{4s}$$

(b)
$$\frac{s(s^4 + 3s^2 + 1)}{(s+1)(s+2)(s+3)(s+4)}$$

(c)
$$\frac{s(s^2+4)}{(s^2+1)(s^2+6)}$$
 (d) $\frac{s(s^2-4)}{(s^2+1)(s^2+6)}$

- 131. A 15V car battery is connected to a 2μ F capacitor computing energy that will be stored in the capacitor is
 - (a) 30×10^{-6} joule (b) 2.25×10^{-4} joule
 - (c) 15×10^{-6} joule (d) none of the above
- 132. Consider the circuit in the figure below. The power delivered by the 30 V source is



. ,					
(c)	600	W	(d)	40	W

- 133. Assertion (A): Millaman's theorem helps in re-
- placing a number of current sources in parallel by a single current source

Reason (R): Maximum power transfer theorem is applicable only for dc, circuits.

- (a) Both Assertion (A) and Reason (R) are individually true and Reason (R) is the correct explanation of Assertion (A)
- (b) Both Assertion (A) and Reason (R) are individually true but Reason (R) is not the correct explanation of Assertion (A)
- (c) Assertion (A) is true but Reason (R) is false
- (d) Assertion (A) is false but Reason (R) is true

134. In the circuit shown in the given figure, the current I through R_L is



(c) 10 A (d) -5 A

135. Find V_{AB} for the circuit shown below



- 136. Optical fibers are preferred as communication links for laser because they
 - (a) prevent interference by other lasers
 - (b) ensure that the beam does not spread
 - (c) prevent atmospheric interference
 - (d) ensure amplification of the signal

T • 4 **T**

137. Match List-I with List II and select the correct answer using the codes given in the below list

T • 4 TT

	List I				List II	
(Ne	etwork	Theor	rems)	(Property)		
A.	Recipr	ocity		1.	Impedance matching	
В.	Tellege	en's		2.	Bilateral	
C.	Superp	ositior	1	3.	$\sum_{k=0}^{b}V_{k}I_{k}=0$	
D.	Maxim	um Po	ower	4.	Linear	
	transfe	r				
				5.	Non linear	
Code:	Α	В	С	D		
(a)	2	4	3	1		

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Ele	ctronics	Engg.		ENC	GINEEF	RS /	ACADEM	1		15
	(b) 2	3	4	1		144.]	Hall effect can be	used to	o measure	
	(c) 2	3	5	1			1. Conductivity o	f the cl	harge carrier.	
	(d) 1	2	3	5		2. Mobility of the charge carrie			e carrier	
138	Asssume	the val	ence	electron is remo	oved from a		3. The number of	f valend	ce electrons pe	r atom
	copper ato	om. The	e net	charge of the ato	om becomes	2	4. Band gap of the	ne mate	rial.	
	(a) +1			(b) +4		1	Which of the follo	owing is	s correct?	
	(c) 0			(d) –1		((a) 2 and 3	(b)) 1 and 2	
139	Surface le	eakage	curre	nt is part of the	e	((c) 3 and 4	(d)) 1 and 4	
	(a) forwar	rd curr	ent			145. T	The minority carrier in a semiconductor r	r life tin naterial	ne and diffusion are 100 µs and	constant 100 cm ² /
	(b) Rever	se curr	ent			5	s, respectively. The	diffusio	on length will b	e
	(c) Rever	se brea	akdow	'n		((a) 100 cm	(b)) 0.01 cm	
	(d) Forward breakdown					((c) 0.1 cm	(d)) 0.2 cm	
140	When a d tion of fr	liode is ee elec	forw trons	and holes may	recombina- produce	146.	The load instruct a transfer from n known as	ion is n nemory	nostly used to a to a processor	lesignate register
	(a) Heat			(b) Radiation			(a) Accumulator		(b) Instruction	nregister
	(c) Light			(d) All of the	above		(c) Program coun	iters		C
141	A geostati	onary s	atellit	e located at abou	it 35000 km		(d) Memory addr	ess regi	ister	
	(a) compl	n can c lete sur	over face	of earth		147.	A group of bits that specific operation	nat tell t on is kr	he computer to nown as	perform
	(b) one he (c) one si	emisphe ide of e	ere in earth	one pass			(a) Instruction co	de	(b) Micro-op	eration
	(d) an area depending on antenna used.				ed.	(C) Accumulator (d)			(u) Register	1) Register
142	Which on	e of the	e follo	owing is not an	LED mate-	148.	The time interval	betwee	n adjacent bits	is called
	rial (a) GaAs			(b) GaP			(a) Word-time(c) Turn around t	ime	(b) Bit-time(d) Slice time	e
	(c) SiC			(d) SiO ₂		149.	The average time	e requi	red to reach a	storage
143	Consider	the folger	llowir rial:	ig statements fo	or a photo-		location in memo	ory and	l obtain its co	ntents is
	1. Its da	rk con	ductiv	ity is small			(a) seek time		(b) turnarour	nd time
	2. With	the abs	orptic	on of radiation,	equal num-		(c) access time		(d) transfer	time
	ber of electrons and holes are produced		oduced	150.	$(2FAOC)_{16}$ is equivalent to					
	Which of the statements given above is/are cor-			is/are cor-		(a) (195084) ₁₀	100000	1100		
	(a) 1 only	y		(b) 2 only			(D) (UUIUIIIII)	100000	1100) ₂	
	(c) Both	1 and 2	2	(d) Neither 1	nor 2		(c) Both (a) and	(b)		
							(d) None of thes	e		

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Electronics	Engg
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		ANSWER &	& EXP	LANATION
1.	Ans. (b)		28.	Ans. (c)
2.	Ans. (c)		29.	Ans. (b)
3.	Ans. (b)		30.	Ans. (b)
4.	Ans. (a)		31	Ans(a)
5.	Ans. (c)			
6.	Ans. (b)		32.	Ans. (d)
7.	Ans. (d)		33.	Ans. (b)
8.	Ans. (a)		34.	Ans. (a)
9.	Ans. (a)		35.	Ans. (a)
10.	Ans. (c)		36.	Ans. (d)
11.	Ans. (d)		37.	Ans. (c)
12.	Ans. (d)		38	Ans(a)
13.	Ans. (d)			Ans. (u)
14.	Ans. (a)		39.	Ans. (b)
15.	Ans. (c)		40.	Ans. (b)
16.	Ans. (d)		41.	Ans. (c)
17.	Ans. (d)		42.	Ans. (b)
18.	Ans. (b)		43.	Ans. (d)
19.	Ans. (c)		44.	Ans. (a)
20.	Ans. (b)		45	Ans(a)
21.	Ans. (a)			Arrs. (a)
22.	Ans. (c)		40.	Ans. (c)
23.	Ans. (c)		4/.	Ans. (c) $\mathbf{L} = \mathbf{L} \left(e^{V_{\mathrm{D}}/nV_{\mathrm{T}}} 1 \right)$
24. 25	Ans. (d)			$I_{d} = I_{o}(e^{-D/4} - 1)$
25. 26	Ans. (a)			By considering $\frac{V_D}{nV_T} >> 1$ then
20. 27	Ans. (c)			
21.	Ans. (c)	$= \frac{20 - 0.6}{5.4 + \frac{400}{9}} = 1.98 \text{ mA}$		$\frac{I_{d}}{I_{o}} = e^{V_{D}}/\eta^{V_{T}}$ $V_{D} \qquad (I_{d})$
	V _c =	$= 20 - 1.98 \times 10^{-3} + 5.4 \times 10^{-3}$.0 ³	$\frac{D}{\eta V_{\rm T}} = ln \left(\frac{\alpha}{\rm I_o}\right)$
	=	= 9.3 V		I _d is constant according to question

 $\boldsymbol{I}_{\rm d}$ is constant according to question,

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$$\frac{V_{D1}}{V_{D2}} = \frac{T_1}{T_2} \Rightarrow V_{D2} = \frac{V_{D1} \cdot T_2}{T_1}$$
$$= \frac{700 \times 10^{-3} (273 + 40)}{(20 + 273)}$$
$$= 747.78 \text{ mV}$$

- 48. Ans. (c)
- 49. Ans.. (a)
- 50. Ans.. (a)
- 51. Ans. (b)

Propagation vector

$$\mathbf{K}_{\mathbf{i}} = 4\mathbf{a}_{\mathbf{x}} + 3\mathbf{a}_{\mathbf{z}}$$

Unit normal vector to the inter face = \hat{a}_z

Plane containing K_i and \hat{a}_z is y = constantSince E_i is normal to the plane So vertically polarized.

52. Ans. (a)



Since current in the both coil is equal

So $|B_1| = |B_2|$

and in opposite direction

$$\vec{B} = \vec{B}_1 + \vec{B}_2 = 0$$

53. Ans. (b)

Compare the equation

$$E_{Z} = E_{0} \sin \frac{m\pi}{a} x \sin \frac{n\pi}{b} y e^{-j\beta z}$$

a = 5 cm, b = 2 cm

$$\frac{m\pi}{a} = 40\pi$$
$$m = 40a = 40 \times .05 = 2$$
$$\frac{n\pi}{b} = 50\pi$$
$$n = 50b = 50 \times .02 = 1$$

Since E_z will present and wave propagate in z-direction

So $H_z = 0$

54. Ans.. (c)

$$Z_{in} = Z_0 \left(\frac{Z_L + jZ_0 \tan \beta l}{Z_0 + jZ_L \tan \beta l} \right)$$

For short circuit load $Z_L = 0$

$$Z_{sc} = jZ_0 \tan \beta l$$

for
$$\frac{\lambda}{4} < l < \frac{\lambda}{2} \implies \frac{2\pi}{\lambda} \cdot \frac{\lambda}{4} < \beta l < \frac{2\pi}{\lambda} \cdot \frac{\lambda}{2}$$

$$\frac{\pi}{2} < \beta l < \pi$$

between
$$\left(\frac{\pi}{2},\pi\right)$$
 tan βl must be -ve

So input impedance will be capacitive.

55. Ans. (b)

$$\mathbf{E} = -\frac{\mathrm{d}\mathbf{V}}{\mathrm{d}\mathbf{r}} = -\frac{\mathrm{d}}{\mathrm{d}\mathbf{r}} \left(-\frac{\mathrm{6}\mathbf{r}^5}{\mathrm{e}_0}\right)$$

$$=\frac{30r^4}{\epsilon_0}$$

Electric field at r = 1

$$\frac{30}{\epsilon_0} = \frac{Q}{4\pi\epsilon_0}$$

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Electronics Engg.

$$Q = 120\pi$$

56. Ans. (a)

Radiation intensity α frequency

$$\frac{I_1}{I_2} = \frac{f_1}{f_2}$$
$$\frac{I}{I_2} = \frac{f}{f/4}$$
$$I_2 = \frac{I}{4}$$

57. Ans. (a)

$$R = 40\pi^2 \left(\frac{l}{\lambda}\right)^2$$
$$\lambda = \frac{c}{f} = \frac{3 \times 10^8}{600 \times 10^3} = \frac{1}{2} \times 10^3 \text{ m}$$
$$R = 40\pi^2 \left(\frac{50}{500}\right)^2 = 0.4\pi^2$$
$$= \frac{2\pi^2}{5}$$

58. Ans. (b)

$$Z_0 = 75$$
 (Resistive)
 $Z_L = 75 - j40$ (Capacitive load)

To match the line, matching load must be

inductive.

59. Ans. (c)

Phase difference between E_x and $E_y = 90^{\circ}$

$$|\mathbf{E}_{\mathbf{x}}| \neq |\mathbf{E}_{\mathbf{y}}|$$

So elliptically polarized wave.

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60. Ans. (b)

$$\delta = \sqrt{\frac{2}{\omega\mu\sigma}} \text{ for conducting medium}$$

$$\frac{\delta_1}{\delta_2} = \sqrt{\frac{f_2}{f_1}}$$

$$\delta = \sqrt{\frac{f_1}{f_2}} \cdot \delta_1$$

 $=\sqrt{\frac{1}{4}}\cdot\delta_1=\frac{\delta_1}{2}=12.5$ cm

$$V = -N \frac{d\phi}{dt}$$
$$= -100 \frac{d}{dt} (t^3 - 2t) mV$$
$$t = 4 \text{ sec.}$$
$$V = -100 [46] mV$$
$$= -4600 mV = -4.6V$$
$$|V| = 4.6V$$

62. Ans. (d)

at

61. Ans. (c)

- 63. Ans. (a)
- 64. Ans. (d)

Permanent dipole moment

= 1.04 debye unit = $1.04 \times 3.33 \times 10^{-30}$ coulomb-meter Boltzman constant K = 1.38×10^{-23} J/k Room temperature T = 300 k

$$\alpha_0 = \frac{P_P^2}{3kT}$$

$$= \frac{(1.04 \times 3.33 \times 10^{-30})^2}{3 \times 1.3 \times 10^{-23} \times 300}$$

= 0.966 × 10⁻³⁹ Farad-meter²
N = 10²⁷ m⁻³
E = 10⁶ V/m

So orientational polarization

$$\begin{split} P_0 &= N \ \alpha_0 E \\ &= 10^{27} \times 0.966 \times 10^{-39} \times 10^6 \end{split}$$

= 0.966×10^{-6} coulomb meter⁻²

65. Ans. (b) **66**. Ans. (d) 67. Ans. (b) Ans. (d) **68**. **69**. Ans. (b) 70. Ans. (b) 71. Ans. (b)

$$-\frac{\delta_1}{1}-125$$
 cm

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72.	Ans. (d)			
73.	Ans. (a)		$\frac{100\times10}{100}$	
74.	Ans. (c)		$= -\frac{s(s+1)}{100 \times 10}$	
75.	Ans. (b)		$1 + \frac{100 \times 10}{s(s+1)}$	
76. 	Ans. (d)		5(5 + 1)	
77.	Ans. (c)		1000	
78. 70	Ans. (a)		$= -\frac{1000}{s(s+1)+1000}$	
79. 80	Ans. (c)		2(2 · 2) · 2000	
81.	Ans. (a)		1000	
82.	Ans. (b)		= s ² + s + 1000	
83.	Ans. (a)	95. Ans. (b)		
84.	Ans. (a)	96. Ans. (a)		
85.	Ans. (d)	97. Ans. (c)		
86.	Ans. (a)	08 Ans (b)		
87.	Ans. (c)	30. Ans. (<i>b</i>)		
88.	Ans. (c)	99. Ans. (d)		
	lead or lag.	100. Ans. (c)		
89.	Ans. (a)	101. Ans. (c)		
90.	Ans. (d)	102. Ans. (d)		
	Steady state response does not depend on initial conditions.	103. Ans. (d)		
91.	Ans. (a)	104. Ans. (d)		
92.	Ans. (a)	105. Ans. (c)		
93.	Ans. (d)	106. Ans. (b)		
	1	107. Ans. (a)		
	$\frac{1}{i\omega}$ for term the slope is -20 dB/decade or -6	108. Ans (c)		
	dB/octave because $-20 \log 2 = -6 dB$	100. Ans. (b)		
94.	Ans. (c)	10). <i>Ans</i> . (<i>b</i>)		
	With respect to k	110. Ans. (c)		
	S. $^{T} - 1$	111. Ans. (d)		
	with respect to H	112. Ans. (d)		
		113. Ans. (b)		
	$S_k^H = \frac{-GH}{1+GW}$	114. Ans. (c)		
	1+GH	115. Ans. (c)		
		116. Ans. (c)		

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 $e^2(t) = \frac{(\Delta V)^2}{12}$ $\Delta V = \frac{A}{S} = \frac{6.4}{64} = 0.1$ RMS Value = $\sqrt{e^2(t)}$ $=\frac{\Delta V}{\sqrt{12}}=\frac{0.1}{\sqrt{12}}=0.03$ Volt 117. Ans. (c) 118. Ans. (c) 119. Ans. (a) 120. Ans. (b) 121. Ans. (c) Given that $f_i = 455 \text{ kHz}$ $f_s = 1200 \text{ kHz}$ Image frequency = $f_s + 2f_i$ $= 1200 + 2 \times 455$ = 2110 kHz122. Ans. (a) 123. Ans. (c)

124. Ans. (c)

125. Ans. (c)

Three branch are parallel and net current is I. Current through 3W

$$\mathbf{I'}=\frac{\mathbf{I}}{\mathbf{3}}$$



Applying KVL in the loop, we get

 $-8 + 4I + 3 \times \frac{I}{3} = 0$ $I = \frac{8}{5}$ voltage across 3\Omega resistance = 3 \times \frac{I}{3}

$$= 3 \times \frac{\frac{8}{5}}{3} = \frac{8}{5}$$
 V.

9I

126. Ans. (c)

Applying KCL

$$\frac{V}{6} + \frac{V - 3I}{2} = I$$
$$\frac{V + 3V - 9I}{6} = I$$
$$4V = 6I + V/I = \frac{15}{4}\Omega$$

127. Ans. (b)

Consider the series RLC circuit



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$$= \frac{Cs}{LCs^2 + RCs + 1}$$

$$=\frac{\frac{1}{L}s}{s^2+\frac{R}{L}s+\frac{1}{LC}}$$

poles of the function

$$S_1, S_2 = \frac{R}{L} \pm \sqrt{\frac{RL}{L^2} - \frac{4}{LC}}$$

closer the poles $j\omega\text{-}axis$ means smaller is the value of (R/L). Thus,

$$Q = \frac{\omega_o L}{R}$$

If R is small, then higher the value of Q. Thus,

$$2\xi\omega_0 = \frac{R}{L}$$
$$\xi = \frac{R}{2\omega_0 L} = \frac{1}{2Q}$$

The value of Q varies inversely as the damping

ratio is $Q = \frac{1}{2\delta} A$ circuit with low R has high Q,

since $Q = \frac{\omega_o L}{R}$

Hence, Statements (1) and (2) are correct

128. Ans. (b)

In series resonance circuit

$$Q = \frac{f_0}{BW} = \frac{1}{\omega_0 CR}$$

$$R = \frac{BW}{2\pi f_0 C f_0}$$

$$= \frac{10 \times 10^5}{2\pi \times 1.5 \times 10^6 \times 150 \times 10^{-6} \times 1.5 \times 10^{-6}}$$

= 4.7 \Omega

129. Ans. (c)

Convert star to delta network as shown in the following figure



$$= -\left(\frac{1}{3} + \frac{1}{9}\right)$$

$$= -\frac{3+1}{9} = -\frac{4}{9}$$
mho

130. Ans. (c)

$$f(s) = \frac{s^3 + 2s^2 + 2s + 1}{4s}$$

is not positive real function as the difference in power of highest degree terms in N(s) and D(s)is more than 1. For this f(s) difference is 2.

$$f(s) = \frac{s(s^4 + 3s^2 + 1)}{(s+1)(s+2)(s+3)(s+4)}$$

is not a positive real function as N(s) have missing term of s^4 .

$$f(s) = \frac{s(s^2 + 4)}{(s^2 + 1)(s^2 + 6)}$$

represent an LC immittance function with pole zero on $j \boldsymbol{\omega}$ and alternator.

Hence, it is positive real function

$$f(s) = \frac{s(s^2 - 4)}{(s^2 + 1)(s^2 + 6)}$$
 is not posi-

tive real function as it has a zero in the RHS of the s-plane at s = 2.

131. Ans. (b)



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Energy =
$$\frac{1}{2}CV^2$$

$$= \frac{1}{2} \times 2 \times 10^{-6} \times 225$$

= 225 × 10^{-6}
= 2.25 × 10^{-4} Joules

132. Ans. (c)

In the two parallel branches the voltage should be the same

$$6 \times I_R = 3I_R \times R_{eq}$$

 $R_{eq} = 2\Omega$

Hence, current control source can be replaced by a resistance of 2Ω .

Hence net resistance of the network is

$$R = 6||2 = 1.5\Omega$$
Power = $\frac{V^2}{R}$
(30)²

$$=\frac{(30)^2}{1.5\Omega}=600W$$

= 80 - 160 = -80V

139. Ans. (b)

140. Ans. (d)

141. Ans. (c)

142. Ans. (d)

LED Material	Colour of light
GaAs	Red
GaP	Green
Si C	Blue

143. Ans. (c) 144. Ans. (b)

145. Ans. (c)

$$L=\sqrt{D\tau}$$

$$= \sqrt{100 \times 100 \times 10^{-6}}$$

= 0.1 cm

146. Ans. (a)
147. Ans. (a)
148. Ans. (b)
149. Ans. (c)
150. Ans. (b)

000

The venin's resistance = 100||50

$$=\frac{100}{3}$$

The venin's voltage = $\frac{240}{150} \times 50 - \frac{240}{150} \times 100$

Therefore current =
$$\frac{-80}{\frac{100}{3} + 6.67} = -2A$$

135. Ans. (c)

133. Ans. (c)

134. Ans. (b)

136. Ans. (c)

137. Ans. (b)

138. Ans. (a)

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